## SPICE Device Model Si3103DV



Vishay Siliconix

## P-Channel 30 V (D-S) MOSFET

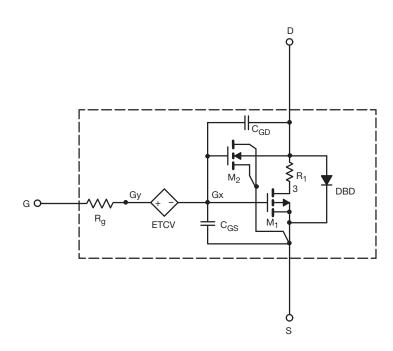
### DESCRIPTION

The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge



### SUBCIRCUIT MODEL SCHEMATIC

#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	1.9	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -7 \text{ A}$	0.0167	0.0168	Ω
		$V_{GS} = -6 V, I_D = -5 A$	0.0200	0.0200	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -7 \text{ A}$	23	24	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = -6.7 A	-0.83	-0.85	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	$V_{DS}$ = -15 V, $V_{GS}$ = 0 V, f = 1 MHz	2090	2005	pF
Output Capacitance	Coss		262	258	
Reverse Transfer Capacitance	C <sub>rss</sub>		230	225	
Total Gate Charge	Qg	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -8.1 \text{ A}$	30	34	nC
		$V_{DS}$ = -15 V, $V_{GS}$ = -4.5 V, $I_{D}$ = -8.1 A	16	16.7	
Gate-Source Charge	Q <sub>gs</sub>		5.8	5.8	
Gate-Drain Charge	Q <sub>gd</sub>		5.4	5.4	

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

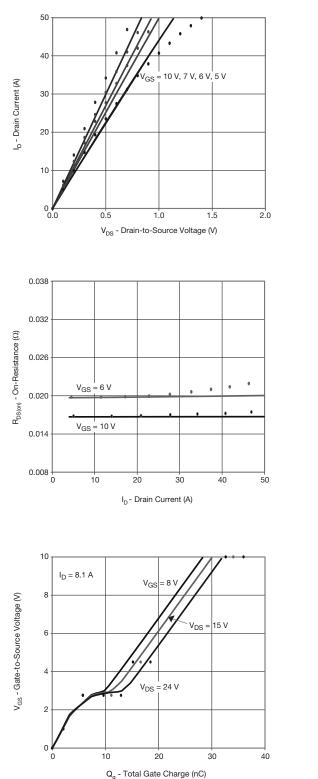
b. Guaranteed by design, not subject to production testing.

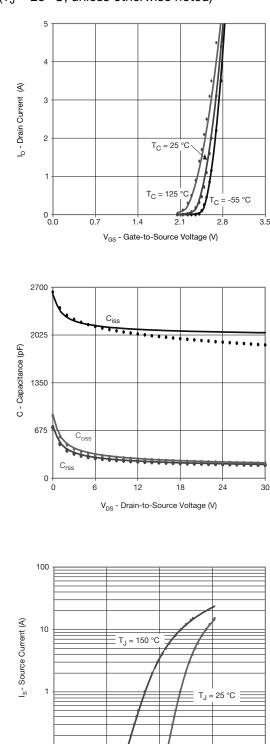
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### COMPARISON OF MODEL WITH MEASURED DATA (T\_J = 25 °C, unless otherwise noted)





Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

S14-1439-Rev. A, 21-Jul-14

3

0.1

Ó

0.3

0.6

V<sub>SD</sub> - Source-to-Drain Voltage (V)

0.9

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1.2

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